

Multi TOPLED® Enhanced Optical Power LED (HOP2000)

LSY T67B



Vorläufige Daten / Preliminary Data

Besondere Merkmale

- **Gehäusotyp:** weißes P-LCC-4 Gehäuse
- **Besonderheit des Bauteils:** mehr Licht durch erhöhten optischen Wirkungsgrad
- **Wellenlänge:** 633 nm (super-rot), 587 nm (gelb)
- **Abstrahlwinkel:** Lambertscher Strahler (120°)
- **Technologie:** InGaAlP
- **optischer Wirkungsgrad:** 14 lm/W (super-rot), 20 lm/W (gelb)
- **Gruppierungsparameter:** Lichtstärke
- **Verarbeitungsmethode:** für alle SMT-Bestücktechniken geeignet
- **Lötmethode:** IR Reflow Löten und Wellenlöten (TTW)
- **Vorbehandlung:** nach JEDEC Level 2
- **Gurtung:** 8 mm Gurt mit 2000/Rolle, ø180 mm oder 8000/Rolle, ø330 mm
- **ESD-Festigkeit:** ESD-sicher bis 2 kV nach EOS/ESD-5.1-1993

Anwendungen

- optischer Indikator
- Hinterleuchtung (LCD, Schalter, Tasten, Displays, Werbebeleuchtung, Allgemeinbeleuchtung)

Features

- **package:** white P-LCC-4 package
- **feature of the device:** more light due to higher optical efficiency
- **wavelength:** 633 nm (super-red), 587 nm (yellow)
- **viewing angle:** Lambertian Emitter (120°)
- **technology:** InGaAlP
- **optical efficiency:** 14 lm/W (super-red), 20lm/W (yellow)
- **grouping parameter:** luminous intensity
- **assembly methods:** suitable for all SMT assembly methods
- **soldering methods:** IR reflow soldering and TTW soldering
- **preconditioning:** acc. to JEDEC Level 2
- **taping:** 8 mm tape with 2000/reel, ø180 mm or 8000/reel, ø330 mm
- **ESD-withstand voltage:** up to 2 kV acc. to EOS/ESD-5.1-1993

Applications

- optical indicators
- backlighting (LCD, switches, keys, displays, illuminated advertising, general lighting)

Typ	Emissions- farbe	Farbe der Lichtaustritts- fläche	Lichtstärke		Bestellnummer
Type	Color of Emission	Color of the Light Emitting Area	Luminous Intensity $I_F = 30 \text{ mA}$ $I_V \text{ (mcd)}$		Ordering Code
			super-red	yellow	
LSY T67B- S1T2-1+T1U2-1	super-red / yellow	colorless clear	180 ... 450	280... 710	Q65110A0661

Helligkeitswerte werden mit einer Stromeinprägedauer von 25 ms und einer Genauigkeit von $\pm 11 \%$ ermittelt.
Luminous intensity is tested at a current pulse duration of 25 ms and a tolerance of $\pm 11 \%$.

Anm.: Die Standardlieferform von Serientypen beinhaltet eine Familiengruppe. Einzelne Gruppen sind nicht erhältlich.

In einer Verpackungseinheit / Gurt ist immer nur eine Gruppe pro Farbe enthalten.

Dimmverhältnis im Gleichstrom-Betrieb max. 5:1

Note: The standard shipping format for serial types includes a family group. Individual groups are not available.

No packing unit / tape ever contains more than one luminous intensity group per color.

Dimming range for direct current mode max. 5:1

Grenzwerte
Maximum Ratings

Bezeichnung Parameter	Symbol Symbol	Werte Values	Einheit Unit
Betriebstemperatur Operating temperature range	T_{op}	– 40 ... + 100	°C
Lagertemperatur Storage temperature range	T_{stg}	– 40 ... + 100	°C
Sperrschichttemperatur Junction temperature	T_j	+ 125	°C
Durchlassstrom Forward current	I_F	50	mA
Stoßstrom Surge current $t \leq 10 \mu s, D = 0.005$	I_{FM}	0.1	A
Sperrspannung ¹⁾ Reverse voltage	V_R	12	V
Leistungsaufnahme Power consumption	P_{tot}	130	mW
Wärmewiderstand Thermal resistance			
Sperrschicht / Umgebung Junction / air	1 chip on $R_{th JA}$	480	K/W
	2 chips on $R_{th JA}$	650	K/W
Sperrschicht / Löt看 Junction / solder point	1 chip on $R_{th JS}$	260	K/W
	2 chips on $R_{th JS}$	360	K/W
Montage auf PC-Board FR 4 (Padgröße $\geq 16 \text{ mm}^2$) mounted on PC board FR 4 (pad size $\geq 16 \text{ mm}^2$)			

¹⁾ für kurzzeitigen Betrieb geeignet / suitable for short term application

Kennwerte ($T_A = 25\text{ °C}$)
Characteristics

Bezeichnung Parameter	Symbol Symbol	Werte Values		Einheit Unit
		LS	LY	
Wellenlänge des emittierten Lichtes (typ.) Wavelength at peak emission $I_F = 30\text{ mA}$	λ_{peak}	645	594	nm
Dominantwellenlänge ¹⁾ (typ.) Dominant wavelength $I_F = 30\text{ mA}$	λ_{dom}	633 ± 6	587 -7/+8	nm
Spektrale Bandbreite bei 50 % $I_{\text{rel max}}$ (typ.) Spectral bandwidth at 50 % $I_{\text{rel max}}$ $I_F = 30\text{ mA}$	$\Delta\lambda$	15	15	nm
Abstrahlwinkel bei 50 % I_V (Vollwinkel) (typ.) Viewing angle at 50 % I_V	2ϕ	120	120	Grad deg.
Durchlassspannung ²⁾ (min.) Forward voltage (typ.) $I_F = 30\text{ mA}$ (max.)	V_F V_F V_F	1.8 2.1 2.4	1.8 2.1 2.4	V V V
Sperrstrom (typ.) Reverse current (max.) $V_R = 12\text{ V}$	I_R I_R	0.01 10	0.01 10	μA μA
Temperaturkoeffizient von λ_{peak} (typ.) Temperature coefficient of λ_{peak} $I_F = 30\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	$TC_{\lambda_{\text{peak}}}$	0.15	0.13	nm/K
Temperaturkoeffizient von λ_{dom} (typ.) Temperature coefficient of λ_{dom} $I_F = 30\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	$TC_{\lambda_{\text{dom}}}$	0.05	0.10	nm/K
Temperaturkoeffizient von V_F (typ.) Temperature coefficient of V_F $I_F = 30\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	TC_V	- 3.4	- 3.7	mV/K
Optischer Wirkungsgrad (typ.) Optical efficiency $I_F = 30\text{ mA}$	η_{opt}	14	20	lm/W

¹⁾ Wellenlängengruppen werden mit einer Stromeinprägedauer von 25 ms und einer Genauigkeit von $\pm 1\text{ nm}$ ermittelt.
Wavelengths are tested at a current pulse duration of 25 ms and a tolerance of $\pm 1\text{ nm}$.

²⁾ Durchlassspannungsgruppen werden mit einer Stromeinprägedauer von 1 ms und einer Genauigkeit von $\pm 0,1\text{ V}$ ermittelt.
Forward voltages are tested at a current pulse duration of 1 ms and a tolerance of $\pm 0.1\text{ V}$.

Helligkeits-Gruppierungsschema
Luminous Intensity Groups

Lichtgruppe Luminous Intensity Group	Lichtstärke Luminous Intensity I_V (mcd)	Lichtstrom Luminous Flux Φ_V (lm)
S1	180 ... 224	600 (typ.)
S2	224 ... 280	760 (typ.)
T1	280 ... 355	950 (typ.)
T2	355 ... 450	1200 (typ.)
U1	450 ... 560	1500 (typ.)
U2	560 ... 710	1900 (typ.)

Gruppenbezeichnung auf Etikett
Group Name on Label

Beispiel: S2-1+T2-1

Example: S2-1+T2-1

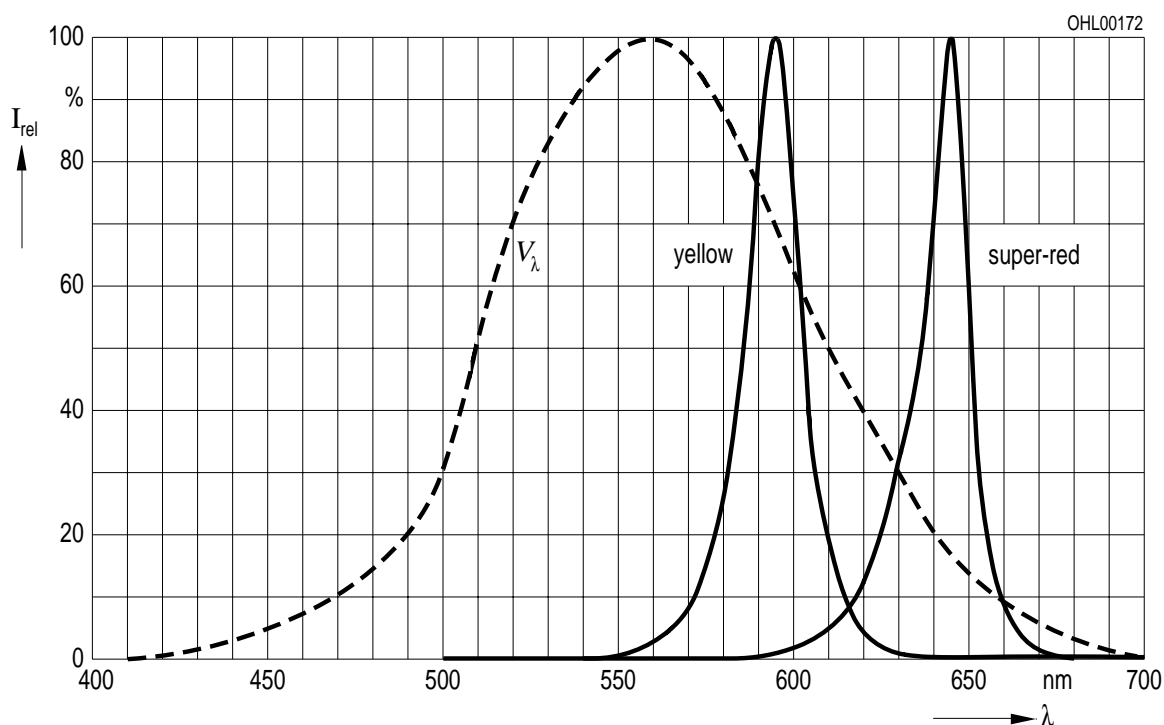
Lichtgruppe (Halbgruppe) Luminous Intensity Half Group	Wellenlänge Wavelength	Lichtgruppe (Halbgruppe) Luminous Intensity Half Group	Wellenlänge Wavelength
super-red		+	yellow
S2	1	+	T2
			1

Relative spektrale Emission $I_{\text{rel}} = f(\lambda)$, $T_A = 25^\circ\text{C}$, $I_F = 30\text{ mA}$

Relative Spectral Emission

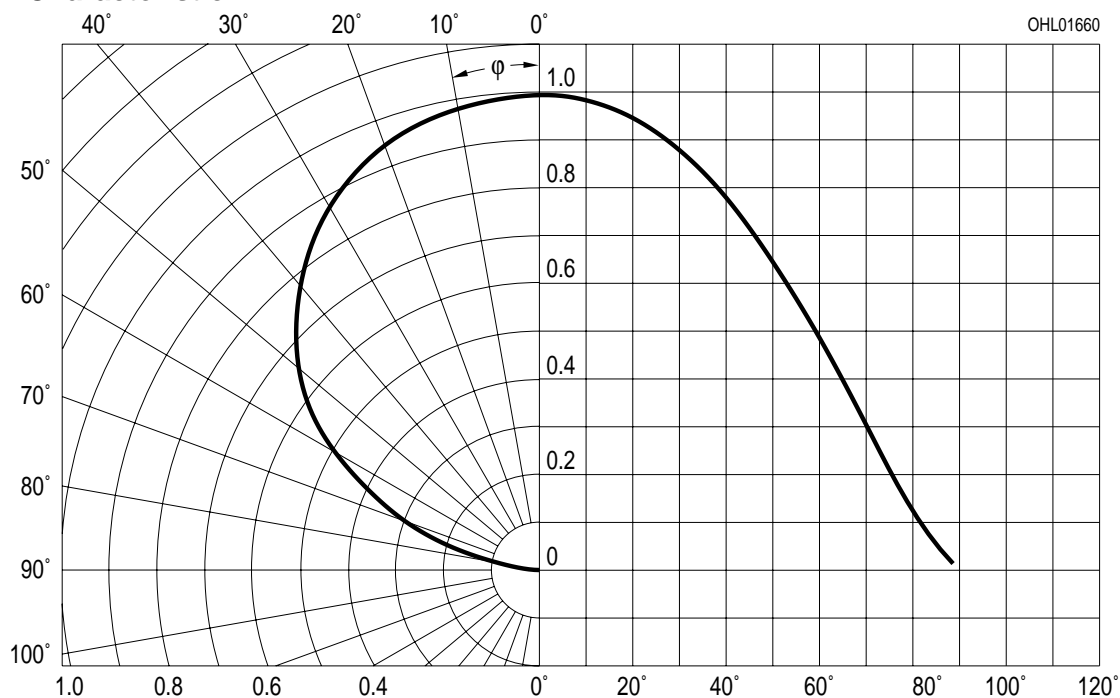
$V(\lambda)$ = spektrale Augenempfindlichkeit

Standard eye response curve



Abstrahlcharakteristik $I_{\text{rel}} = f(\varphi)$

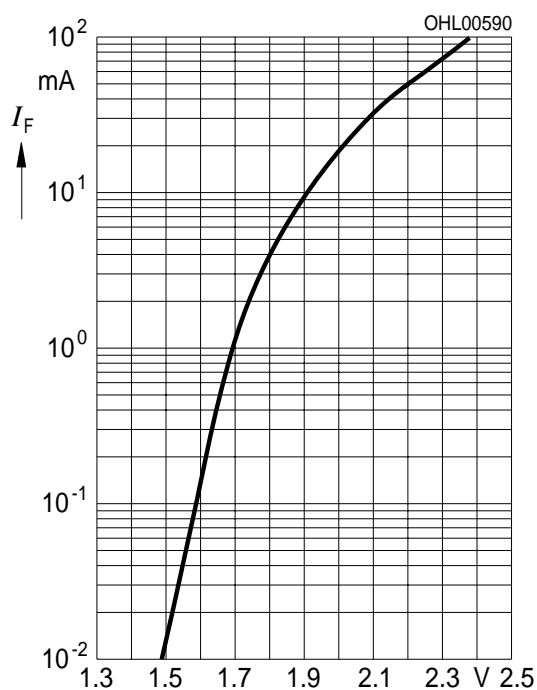
Radiation Characteristic



Durchlassstrom $I_F = f(V_F)$

Forward Current

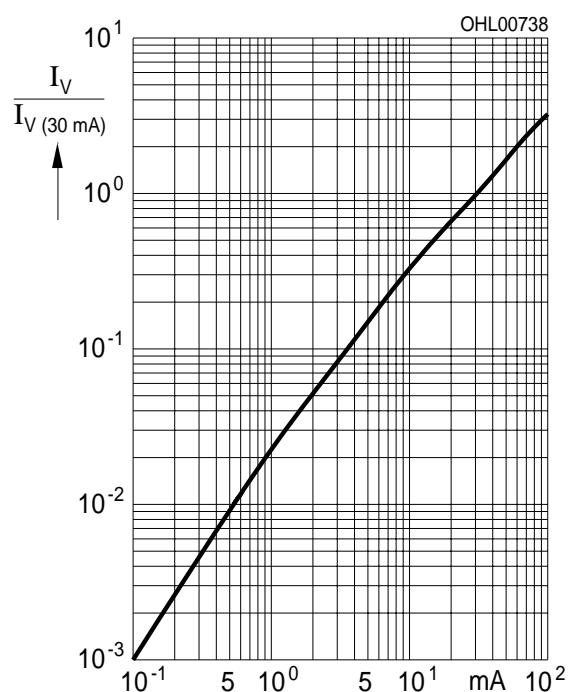
$T_A = 25\text{ °C}$



Relative Lichtstärke $I_V/I_{V(30\text{ mA})} = f(I_F)$

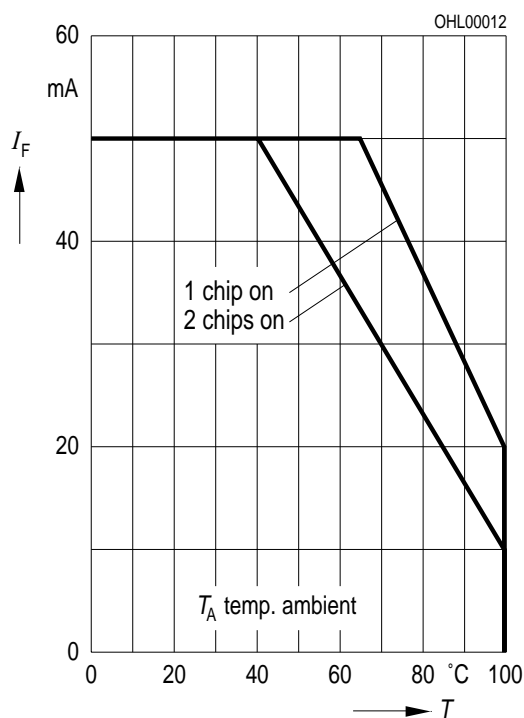
Relative Luminous Intensity

$T_A = 25\text{ °C}$



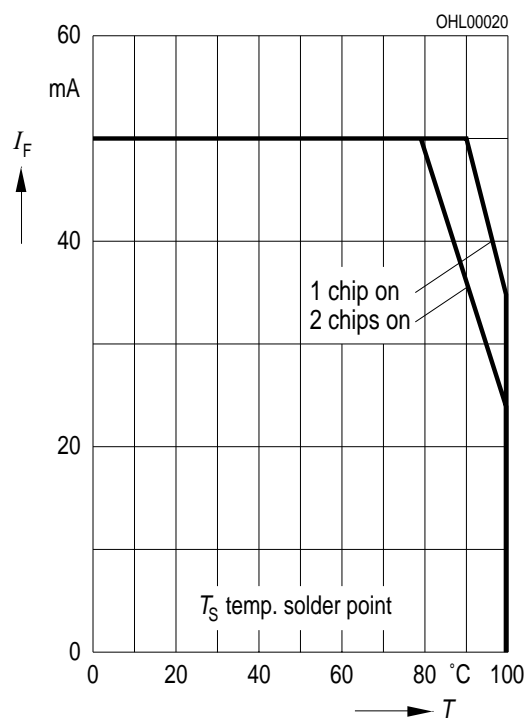
Maximal zulässiger Durchlassstrom $I_F = f(T)$

Max. Permissible Forward Current



Maximal zulässiger Durchlassstrom $I_F = f(T)$

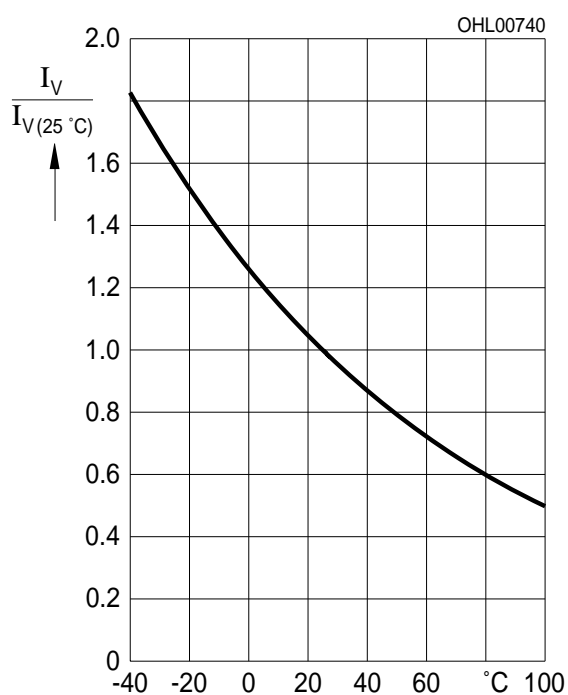
Max. Permissible Forward Current



Relative Lichtstärke $I_V/I_{V(25\text{ °C})} = f(T_A)$

Relative Luminous Intensity

$I_F = 30\text{ mA}$



Zulässige Impulsbelastbarkeit $I_F = f(t_p)$

Permissible Pulse Handling Capability

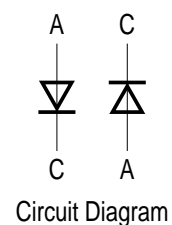
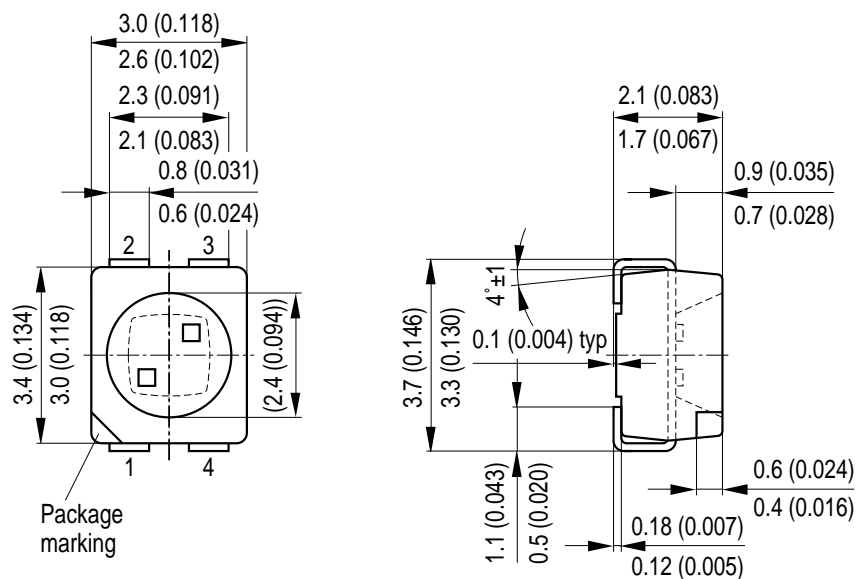
Duty cycle $D = \text{parameter}$, $T_A = 25\text{ °C}$

Zulässige Impulsbelastbarkeit $I_F = f(t_p)$

Permissible Pulse Handling Capability

Duty cycle $D = \text{parameter}$, $T_A = 85\text{ °C}$

Maßzeichnung Package Outlines



GPLY6837

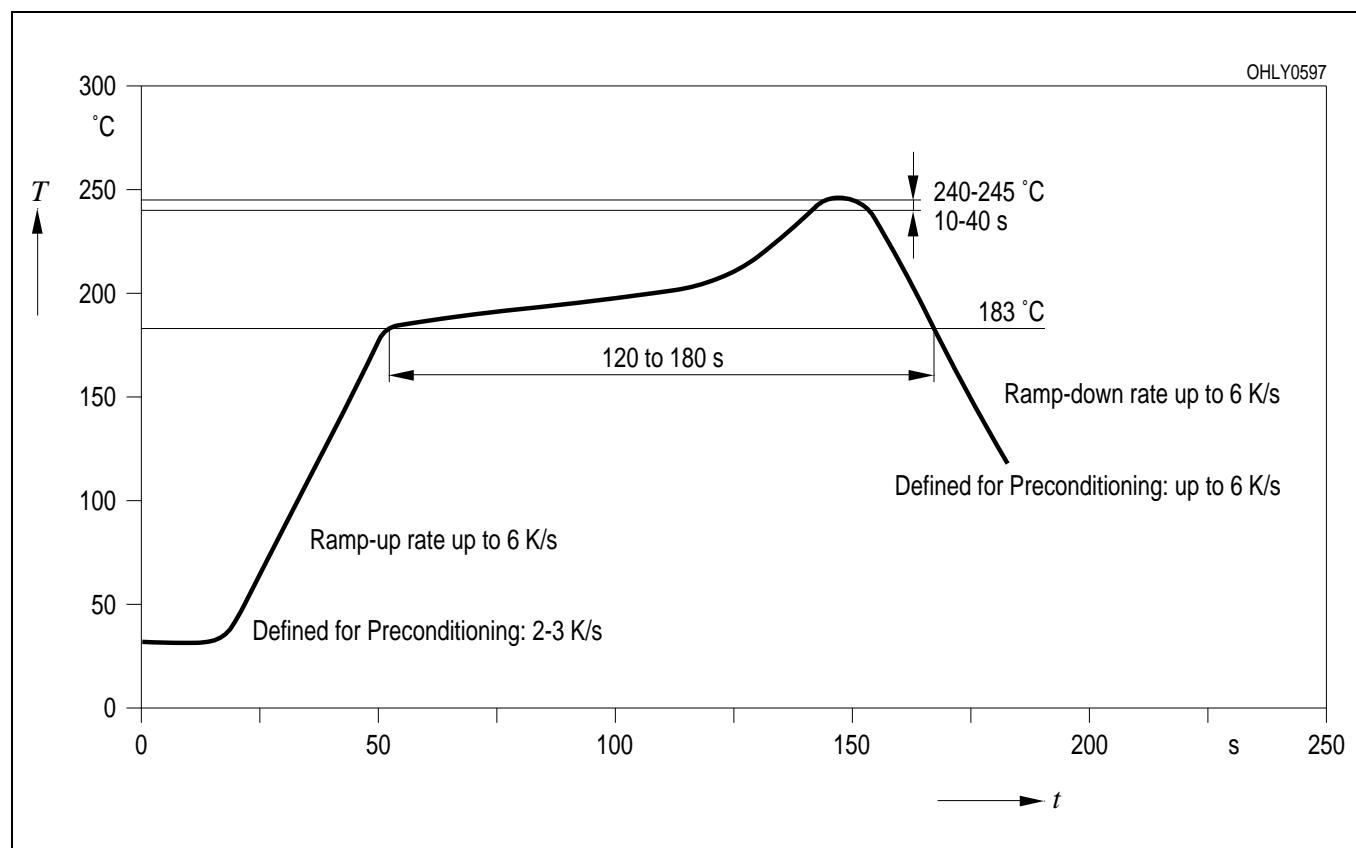
L	S	Y	T67B
LED	Anode: pin 2	Anode: pin 4	Package
	Cathode: pin 1	Cathode: pin 3	

Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

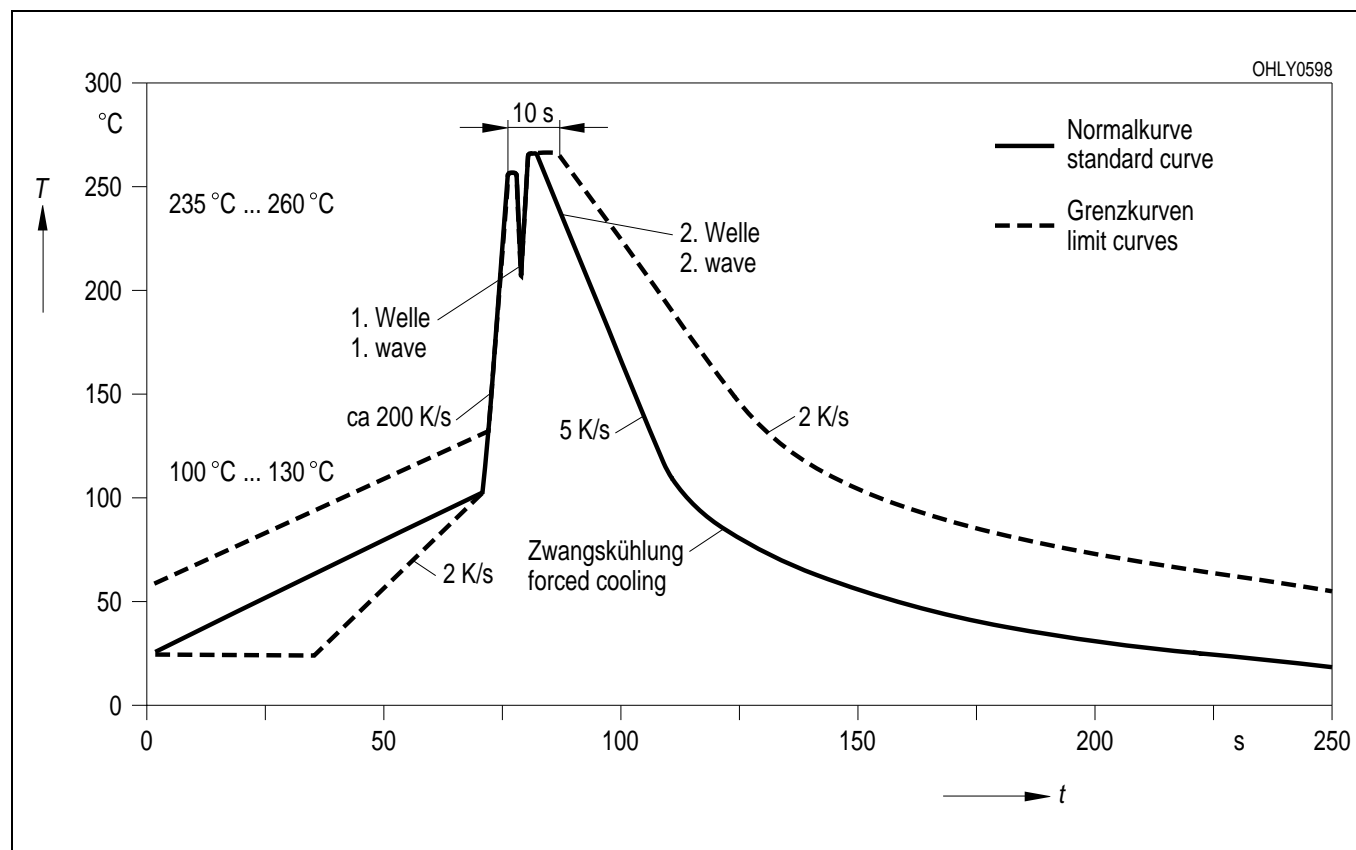
Gewicht / Approx. weight: 35 mg

Lötbedingungen Vorbehandlung nach JEDEC Level 2
Soldering Conditions Preconditioning acc. to JEDEC Level 2

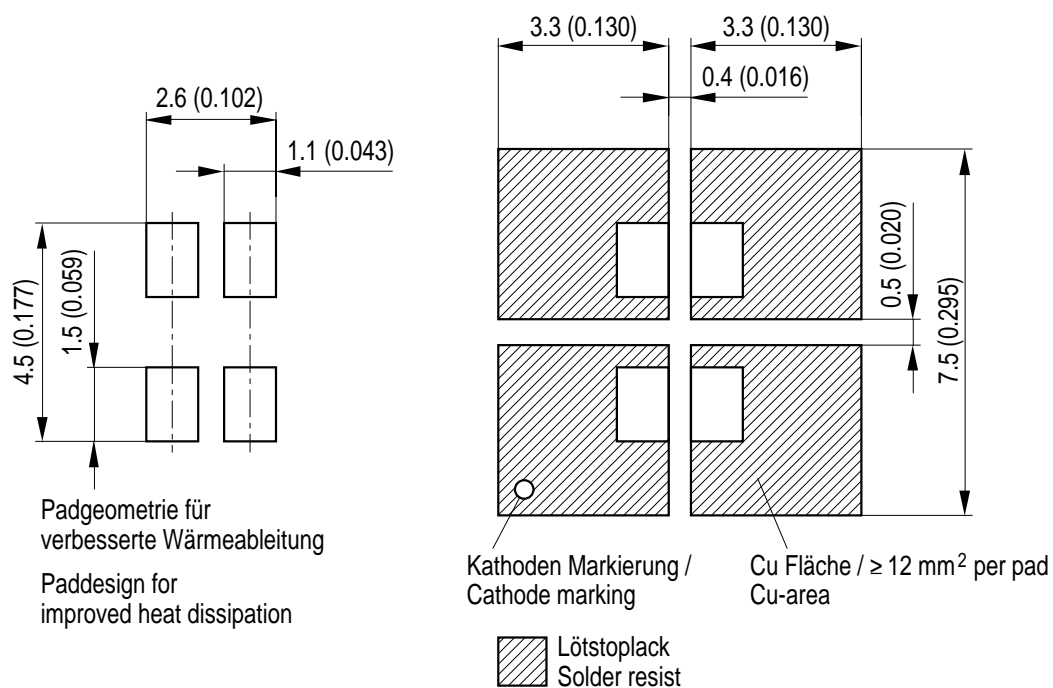
IR-Reflow Lötprofil (nach IPC 9501)
IR Reflow Soldering Profile (acc. to IPC 9501)



Wellenlöten (TTW) (nach CECC 00802)
TTW Soldering (acc. to CECC 00802)



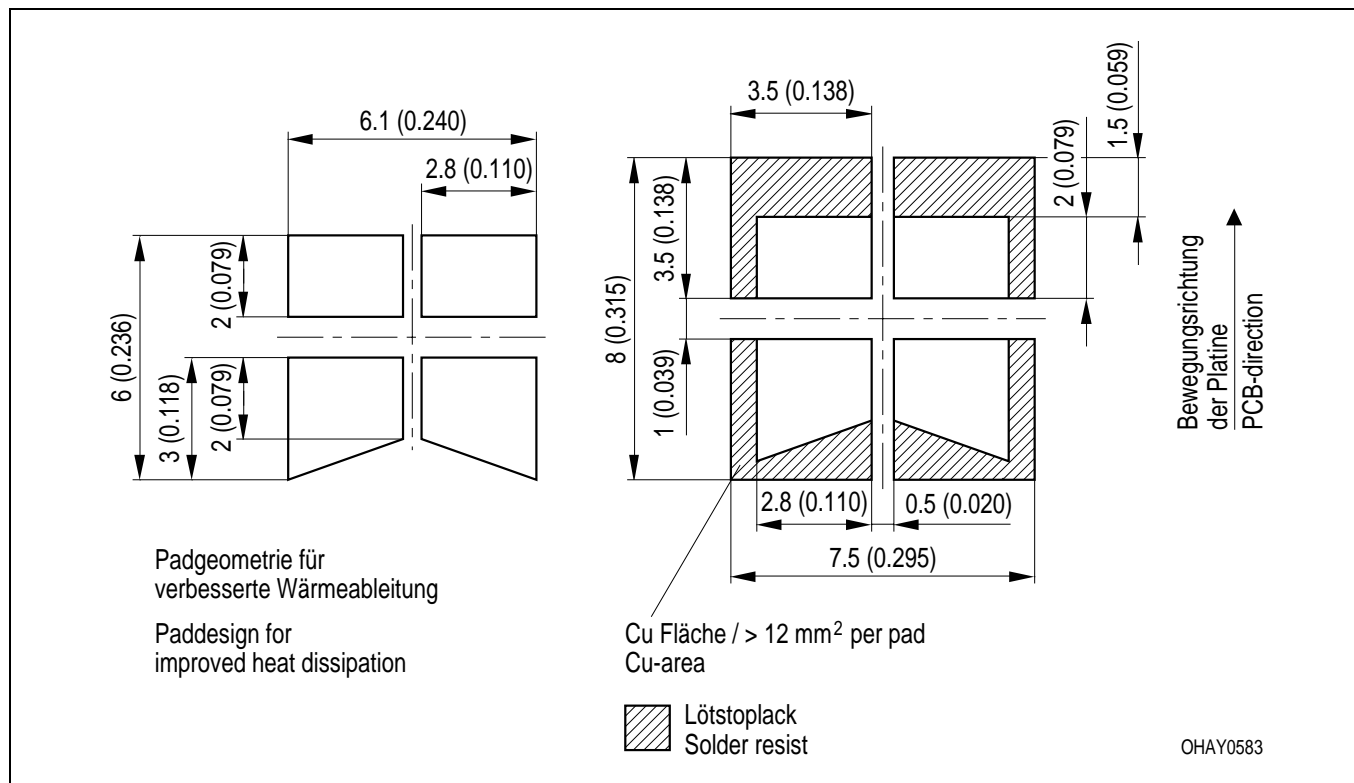
Empfohlenes Lötpad design IR Reflow Lötén
Recommended Solder Pad IR Reflow Soldering



OHLPY439

Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

Empfohlenes Lötpaddesign Wellenlöten (TTW)
Recommended Solder Pad TTW Soldering



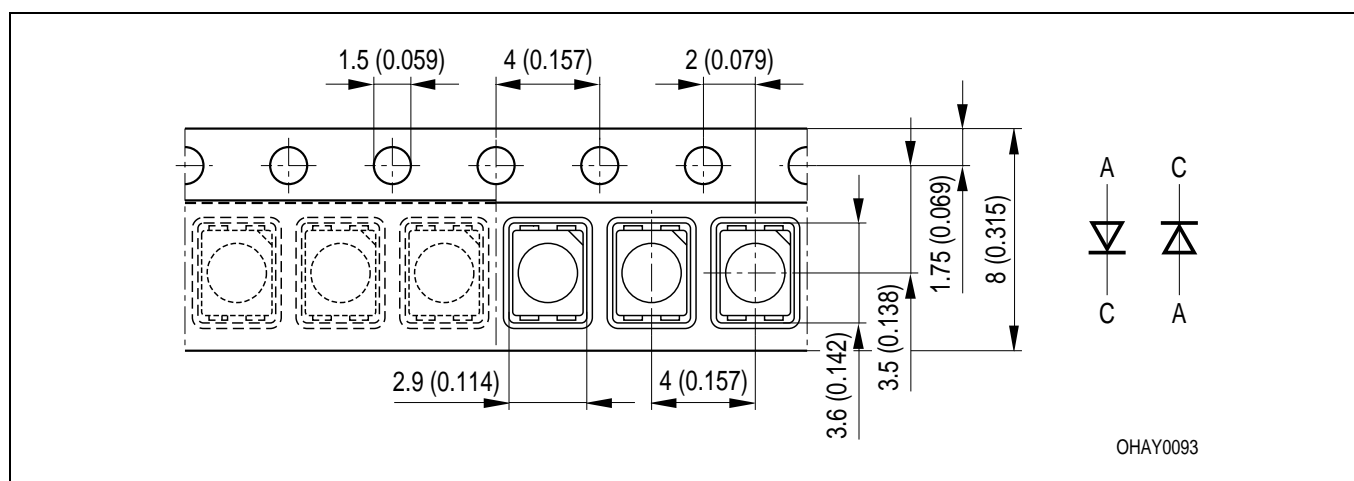
Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

Gurtung / Polarität und Lage

Verpackungseinheit 2000/Rolle, ø180 mm
 oder 8000/Rolle, ø330 mm

Method of Taping / Polarity and Orientation

Packing unit 2000/reel, ø180 mm
 or 8000/reel, ø330 mm



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

Revision History: 2003-02-12		Date of change
Previous Version: 2003-01-14		
Page	Subjects (major changes since last revision)	
14	annotations	2002-07-25
4	value ($TC_{\lambda_{\text{dom}}}$ from 0.06 to 0.05 nm/K)	2002-07-25
3, 4	value (reverse voltage from 5 V to 12 V)	2002-09-18
2	new ordering code	2003-01-14
7	diagram forward current OHL00646 replaced by OHL00590	2003-02-12

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Attention please!

The information describes the type of component and shall not be considered as assured characteristics. All typical data and graphs are basing on representative samples, but don't represent the production range. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.

Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances. For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version in the Internet.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Components used in life-support devices or systems must be expressly authorized for such purpose! Critical components ¹ may only be used in life-support devices or systems ² with the express written approval of OSRAM OS.

¹ A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or the effectiveness of that device or system.

² Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health of the user may be endangered.